勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw



Voltage Variable Absorptive Attenuator 40 dB, 0.5 - 3.0 GHz

Rev. V2

Features

- Single Positive Voltage Control: 0 to +5 Volts
- 40 dB Attenuation Range at 900 MHz
- ± 2 dB Linearity from BSL
- Low DC Power Consumption
- Tape and Reel Packaging Available
- Lead-Free SOIC-8 Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible
- RoHS* Compliant Version of AT-108

Description

M/A-COM's MAAVSS0007 is a GaAs MESFET MMIC voltage variable absorptive attenuator in a lead-free SOIC-8 surface mount plastic package. The MAAVSS0007 is ideally suited for use where linear attenuation, fine tuning and very low power consumption are required.

Typical applications include radio, cellular, GPS equipment and automatic gain/level control circuits.

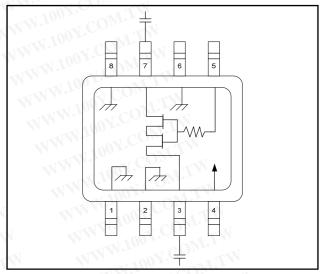
The MAAVSS0007 is fabricated with a monolithic GaAs MMIC using a mature 1-micron process. The process features full chip passivation for increased performance and reliability.

Ordering Information 1,2

Part Number	Package		
MAAVSS0007	Bulk Packaging		
MAAVSS0007TR	1000 piece reel		
MAAVSS0007SMB	Sample Board		

- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 5 loose parts.

Functional Schematic 3,4,5,6



- 3. V_{cc} = +5 VDC @ 50 μ A maximum.
- 4. $V_c = 0$ VDC to +5 VDC @ 50 μ A maximum.
- External DC blocking capacitors are requirements on all RF ports.
- 6. 39 pF used for data measurements.

Pin Configuration

Pin No.	Function	Pin No.	Function	
1.1	Ground	5	V _c	
2	Ground	600	Ground	
3	RF Port	7,00	RF Port	
4	V _{cc}	8	Ground	

Absolute Maximum Ratings 7,8

Parameter	Absolute Maximum	
Input Power	+21 dBm	
Supply Voltage V _{cc}	-1 V <u><</u> V _{CC} <u><</u> +8 V	
Control Voltage V _C	-1 V ≤ V _C ≤ V _{CC} +0.5 V	
Operating Temperature	-40°C to +85°C	
Storage Temperature	-65°C to +150°C	
1 1110 - 11.3	- X 10°	

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- 8. M/A-COM does not recommend sustained operation near these survivability limits.
- * Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
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 Visit www.macomtech.com for additional data sheets and product information.



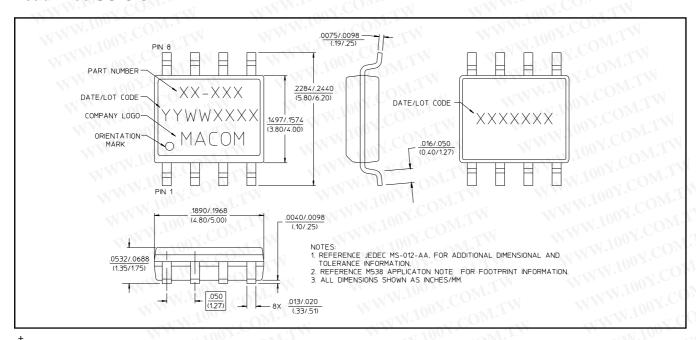
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Electrical Specifications: $T_A = 25$ °C, $Z_0 = 50 \Omega$

Parameter	Test Conditions	Units	√ Min.	Тур.	Max.
Insertion Loss	0.5 - 1.0 GHz 1.0 - 3.0 GHz	dB dB	W <u>_</u>	2.5 2.6	— 3.5
Attenuation	0.5 - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz	dB dB dB	35	43 40 33	
Flatness (peak-to-peak)	0.5 - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz	dB dB dB	W.T.A.	± 0.5 ± 1.2 ± 1.5	
VSWR	0.5 - 3.0 GHz	Ratio	OW.	2:1	_
Trise, Tfall	10% to 90% RF, 90% to 10% RF	μS	$CO_{\overline{M}^{1,1}}$	15	_
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	μS	COM.	25	_
Transients	In-Band	mV	- coM	12	_

Lead-Free SOIC-8¹



 $^{^{\}dagger}$ Reference Application Note M538 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements.

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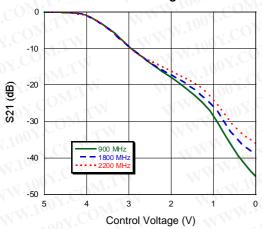


Voltage Variable Absorptive Attenuator 40 dB, 0.5 - 3.0 GHz

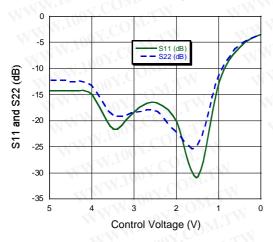
Rev. V2

Typical Performance Curves @ 25°C

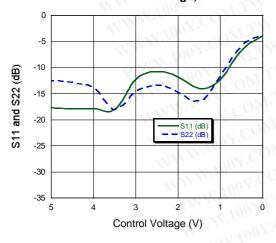
Attenuation vs. Control Voltage



Return Loss vs. Control Voltage, F = 900 MHz

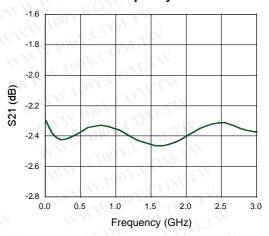


Return Loss vs. Control Voltage, F = 2200 MHz

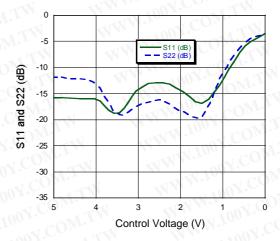


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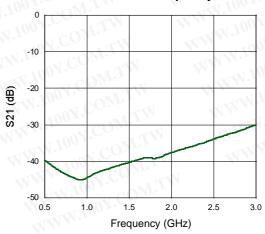
Insertion Loss vs. Frequency



Return Loss vs. Control Voltage, F = 1800 MHz



Maximum Attenuation vs. Frequency



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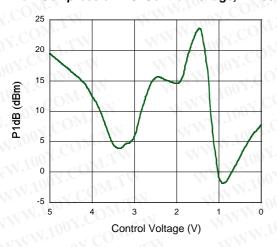


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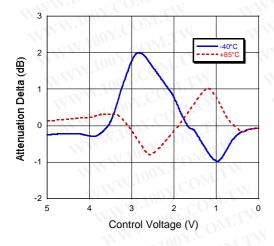
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Typical Performance Curves @ 25°C

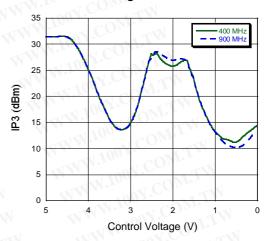
1 dB Compression vs. Control Voltage, F = 900 MHz



Attenuation vs. Temperature Normalized to 25°C, F = 900 MHz



IP3 vs. Control Voltage



Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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